BTA204S-600D 3Q Hi-Com Triac Rev. 6 — 9 May 2011

Product data sheet

1. **Product profile**

1.1 General description

Planar passivated three quadrant triac in a SOT428 (DPAK) surface-mountable plastic package. This "series D" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers and logic ICs including microcontrollers.

1.2 Features and benefits

- 3Q technology for improved noise immunity
- Direct gate triggering from low power drivers and logic ICs
- High blocking voltage capability
- High commutation capability

- Planar passivated for voltage ruggedness and reliability
- Surface-mountable package
- Triggering in three quadrants only
- Very sensitve gate for easy logic level triggering

1.3 Applications

- AC solenoids
- General purpose motor control circuits

Home appliances

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 ^{\circ}C; t_p = 20 \text{ms};$ see Figure 4; see Figure 5	-	-	25	Α
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{mb} \le 107 ^{\circ}\text{C}$; see Figure 1; see Figure 2; see Figure 3	-	-	4	Α



Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+$ G+; $T_j = 25 \text{ C};$ see Figure 7	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+$ G-; $T_j = 25 \text{ C};$ see <u>Figure 7</u>	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2-G-; T_j = 25 °C;$ see Figure 7	-	-	5	mA

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		. .
2	T2	main terminal 2	mb	T2 T1
3	G	gate		`G sym051
mb	T2	mounting base; main terminal 2	1 3	
			SOT428 (DPAK)	

3. Ordering information

Table 3. Ordering information

Type number Package			
	Name	Description	Version
BTA204S-600D	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

_				
Parameter	Conditions	Min	Max	Unit
repetitive peak off-state voltage		-	600	V
RMS on-state current	full sine wave; $T_{mb} \le 107 \text{C}$; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	4	Α
non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ C}$; $t_p = 20 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	25	Α
	full sine wave; $T_{j(init)} = 25 \text{ C}$; $t_p = 16.7 \text{ ms}$	-	27	Α
I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	3.1	A^2s
rate of rise of on-state current	$I_T = 6 \text{ A}$; $I_G = 0.2 \text{ A}$; $dI_G/dt = 0.2 \text{ A/}\mu\text{s}$	-	100	A/µs
peak gate current		-	2	Α
peak gate power		-	5	W
average gate power	over any 20 ms period	-	0.5	W
storage temperature		-40	150	C
junction temperature		-	125	C
r	repetitive peak off-state voltage RMS on-state current non-repetitive peak on-state current 12t for fusing rate of rise of on-state current peak gate current peak gate power average gate power storage temperature	repetitive peak off-state voltage RMS on-state current	repetitive peak off-state voltage RMS on-state current full sine wave; $T_{mb} \le 107 ^{\circ}\text{C}$; see Figure 2; see Figure 3 non-repetitive peak on-state full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; t _p = 20 ms; see Figure 4; see Figure 5 full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; - t _p = 16.7 ms $I^2\text{t for fusing}$ t _p = 10 ms; sine-wave pulse - rate of rise of on-state current $I_T = 6 A$; $I_G = 0.2 A$;	repetitive peak off-state voltage - 600 RMS on-state current full sine wave; $T_{mb} \le 107 ^{\circ} \text{C}$; see Figure 2; see Figure 3 - 25 current full sine wave; $T_{j(init)} = 25 ^{\circ} \text{C}$; $-25 ^{\circ} \text{C}$; $-27 ^{$

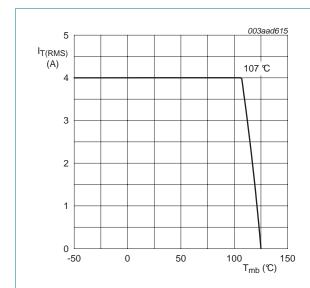
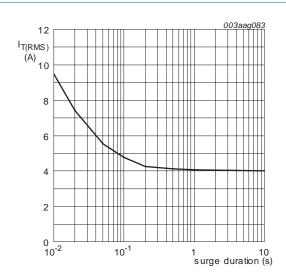


Fig 1. RMS on-state current as a function of mounting base temperature; maximum values



f = 50 Hz; T_{mb} = 107 °C

Fig 2. RMS on-state current as a function of surge duration; maximum values

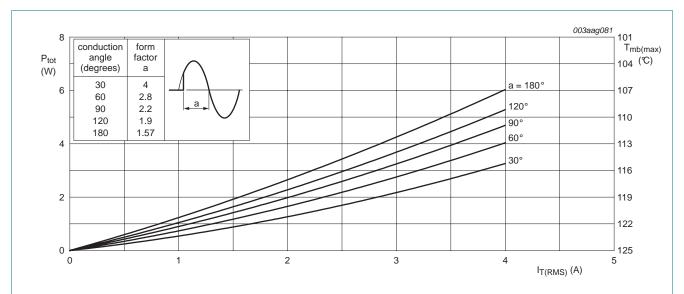
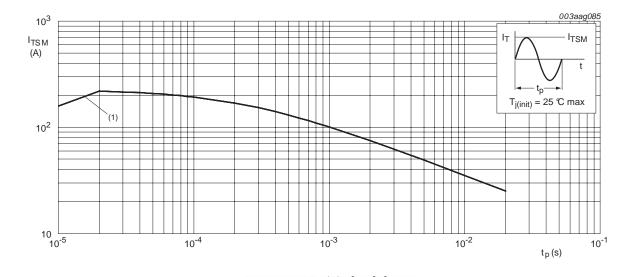
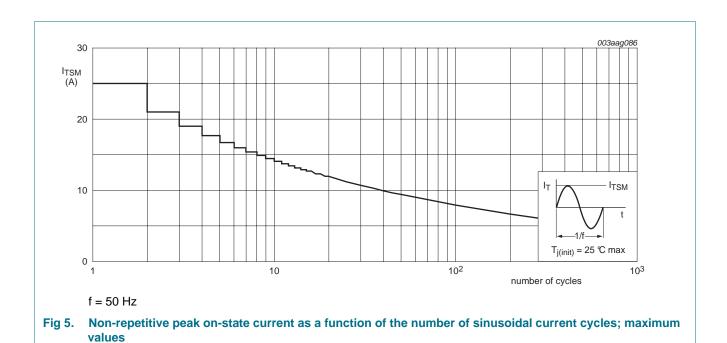


Fig 3. Total power dissipation as a function of RMS on-state current; maximum values



 $t_p \ \leq \ 20 \ ms; \ \ (1) \ \ dI_T/dt \ limit$

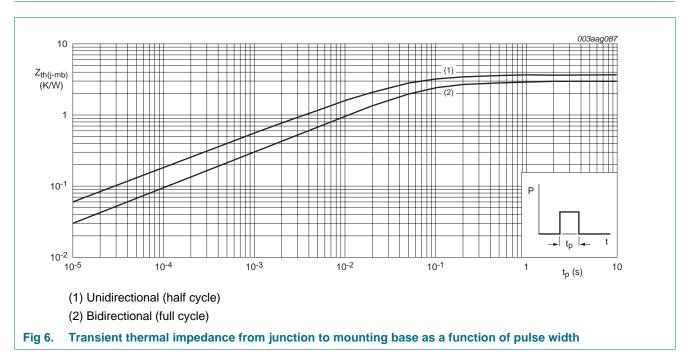
Fig 4. Non-repetitive peak on-state current as a function of pulse width; maximum values



5. Thermal characteristics

Table 5. Thermal characteristics

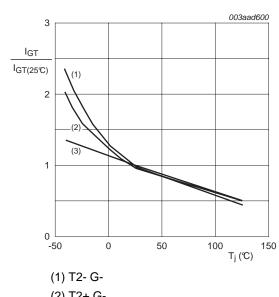
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	full cycle; see Figure 6	-	-	3	K/W
		half cycle; see Figure 6	-	-	3.7	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air; printed circuit board (FR4) mounted	-	75	-	K/W



6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT} gat	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 7}}{}$	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ \text{ G-};$ $T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 7}}{}$	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2- \text{G-};$ $T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 7}}{}$	-	-	5	mA
I _L latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 8}}{}$	-	-	6	mA	
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 8}}{}$	-	-	9	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 8}}{}$	-	-	6	mA
l _H	holding current	$V_D = 12 \text{ V}; T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 9}}{}$	-	-	6	mΑ
V _T	on-state voltage	$I_T = 5 \text{ A}$; $T_j = 25 \text{ C}$; see Figure 10	-	1.4	1.7	V
V _{GT} gate trigger vo	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ C};$ see Figure 11	-	0.7	1.5	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 \text{ C};$ see Figure 11	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 ℃	-	0.1	0.5	mΑ
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; T_j = 125 \text{C}; exponential}$ waveform; gate open circuit	20	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; T_j = 125 \text{ °C}; I_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 0.1 \text{ V/}\mu\text{s}; gate open circuit}$	4.5	-	-	A/m
		$V_D = 400 \text{ V}; T_j = 125 \text{ °C}; I_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 10 \text{ V/}\mu\text{s};$ gate open circuit	1.1	-	-	A/m
t _{gt}	gate-controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = 600 \text{ V}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A/}\mu\text{s}$	-	2	-	μs



- (2) T2+ G-
- (3) T2+ G+

Fig 7. Normalized gate trigger current as a function of junction temperature

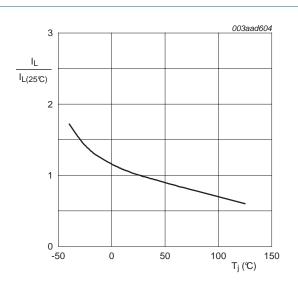
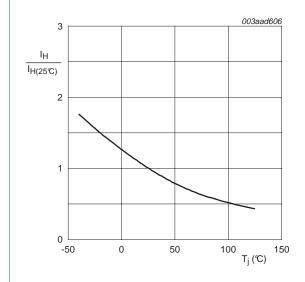
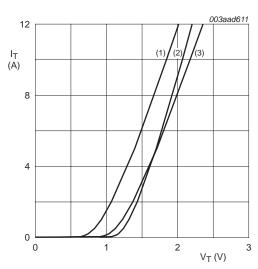


Fig 8. Normalized latching current as a function of junction temperature



Normalized holding current as a function of Fig 9. junction temperature



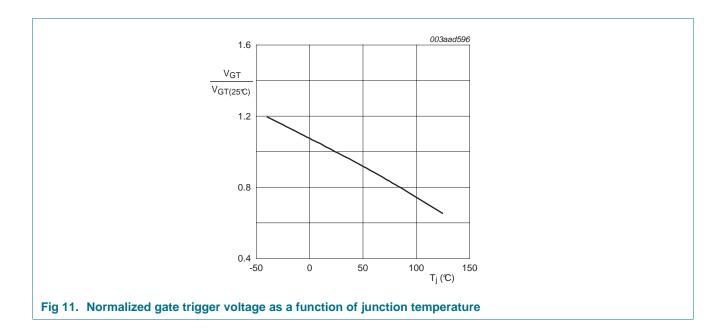
Vo = 1.27 V; Rs = 0.091 Ω

(1) Tj = 125 ℃; typical values

(2) Tj = 125 ℃; maximum values

(3) Tj = 25 ℃; maximum values

Fig 10. On-state current as a function of on-state voltage



7. Package outline

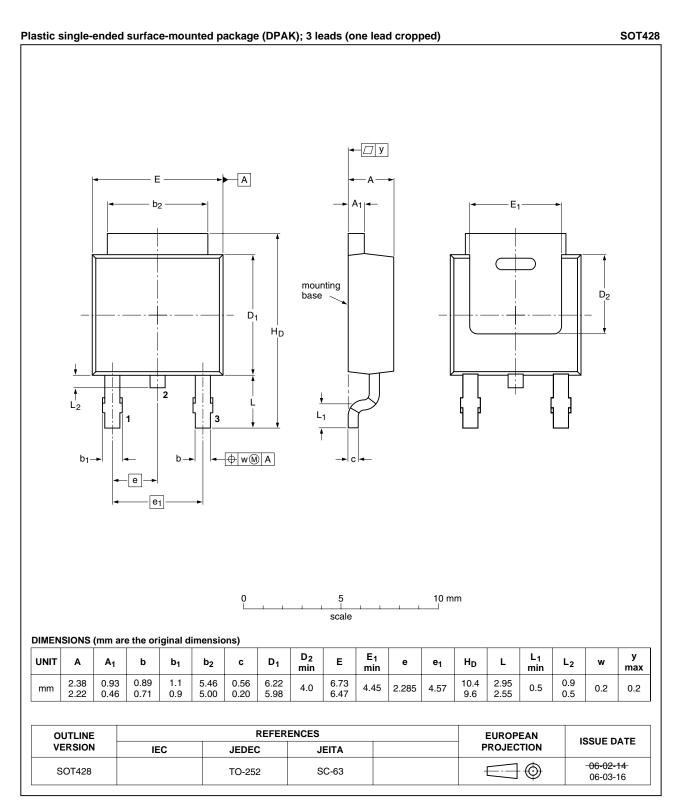


Fig 12. Package outline SOT428 (DPAK)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA204S-600D v.6	20110509	Product data sheet	-	BTA204S_SER_D_E_F_5
Modifications:		t of this data sheet has b of NXP Semiconductors	•	comply with the new identity
	 Legal texts 	have been adapted to t	he new company na	ame where appropriate.
	 Type numb 	oer BTA204S-600D sepa	rated from data she	eet BTA204S_SER_D_E_F_5.
BTA204S_SER_D_E_F_5	20060216	Product specification	-	BTA204S_SER_D_E_F_4

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9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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